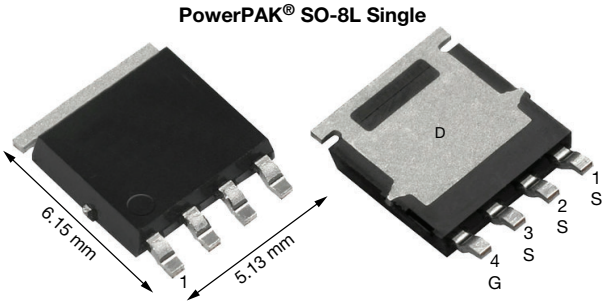
N-Channel 40 V (D-S) MOSFET

PowerPAK® SO-8L Single



Top View Bottom View

FEATURES

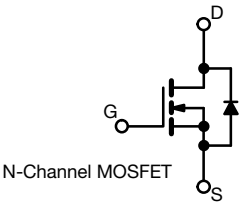
- TrenchFET® Gen IV power MOSFET
- Very low Q_g and Q_{oss} reduce power loss and improve efficiency
- Flexible leads provide resilience to mechanical stress
- 100 % R_g and UIS tested
- Q_{gd}/Q_{gs} ratio < 1 optimizes switching characteristics
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
HALOGEN FREE

PRODUCT SUMMARY	
V_{DS} (V)	40
$R_{DS(on)}$ max. (Ω) at V_{GS} = 10 V	0.0023
$R_{DS(on)}$ max. (Ω) at V_{GS} = 4.5 V	0.00335
Q_g typ. (nC)	21.5
I_D (A) [a]	126
Configuration	Single

APPLICATIONS

- Synchronous rectification
- High power density DC/DC
- DC/AC inverters



N-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and halogen-free	SIJA54ADP-T1-GE3

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V_{DS}	40	V
Gate-source voltage		V_{GS}	+20, -16	
Continuous drain current (T_J = 150 °C)	T_C = 25 °C	I_D	126	A
	T_C = 70 °C		100	
	T_A = 25 °C		35.4 [b, c]	
	T_A = 70 °C		28.3 [b, c]	
Pulsed drain current (t = 100 µs)		I_{DM}	300	
Continuous source-drain diode current	T_C = 25 °C	I_S	59.7	
	T_A = 25 °C		4.7 [b, c]	
Single pulse avalanche current	L = 0.1 mH	I_{AS}	25	
Single pulse avalanche energy		E_{AS}	31.25	mJ
Maximum power dissipation	T_C = 25 °C	P_D	65.7	W
	T_C = 70 °C		42.1	
	T_A = 25 °C		5.2 [b, c]	
	T_A = 70 °C		3.3 [b, c]	
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +150	°C
Soldering recommendations (peak temperature) [d, e]			260	

THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction to ambient [b, f]	t ≤ 10 s	R_{thJA}	20	24	°C/W
Maximum junction to case (drain)	Steady state	R_{thJC}	1.5	1.9	

Notes

a. T_C = 25 °C
b. Surface mounted on 1" x 1" FR4 board
c. t = 10 s
d. See solder profile (www.vishay.com/doc?73257). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components
f. Maximum under steady state conditions is 62.5 °C/W

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SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static						
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0 V, I_D = 1 mA	40	-	-	V
V_{DS} temperature coefficient	$\Delta V_{DS}/T_J$	I_D = 1 mA	-	25	-	mV/°C
$V_{GS(th)}$ temperature coefficient	$\Delta V_{GS(th)}/T_J$	I_D = 250 µA	-	-5.2	-	
Gate-source threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA	1	-	2.5	V
Gate-source leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = +20, -16 V	-	-	± 100	nA
Zero gate voltage drain current	I_{DSS}	V_{DS} = 40 V, V_{GS} = 0 V	-	-	1	µA
		V_{DS} = 40 V, V_{GS} = 0 V, T_J = 75 °C	-	-	20	
Drain-source on-state resistance [a]	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 15 A	-	0.0019	0.0023	Ω
		V_{GS} = 4.5 V, I_D = 15 A	-	0.0027	0.00335	
Forward transconductance [a]	g_{fs}	V_{DS} = 10 V, I_D = 15 A	-	98	-	S
Dynamic [b]						
Input capacitance	C_{iss}	V_{DS} = 20 V, V_{GS} = 0 V, f = 1 MHz	-	3850	-	pF
Output capacitance	C_{oss}		-	655	-	
Reverse transfer capacitance	C_{rss}		-	75	-	
Total gate charge	Q_g	V_{DS} = 20 V, V_{GS} = 10 V, I_D = 10 A	-	46.5	70	nC
		V_{DS} = 20 V, V_{GS} = 4.5 V, I_D = 10 A	-	21.5	32	
Gate-source charge	Q_{gs}		-	9.3	-	
Gate-drain charge	Q_{gd}		-	4	-	
Output charge	Q_{oss}	V_{DS} = 20 V, V_{GS} = 0 V	-	24.5	-	
Gate resistance	R_g	f = 1 MHz	0.5	1.1	1.8	Ω
Turn-on delay time	$t_{d(on)}$	V_{DD} = 20 V, R_L = 2 Ω I_D ≅ 10 A, V_{GEN} = 10 V, R_g = 1 Ω	-	15	30	ns
Rise time	t_r		-	6	12	
Turn-off delay time	$t_{d(off)}$		-	32	64	
Fall time	t_f		-	6	12	
Turn-on delay time	$t_{d(on)}$	V_{DD} = 20 V, R_L = 2 Ω I_D ≅ 10 A, V_{GEN} = 4.5 V, R_g = 1 Ω	-	26	52	
Rise time	t_r		-	63	126	
Turn-off delay time	$t_{d(off)}$		-	30	60	
Fall time	t_f		-	10	20	
Drain-Source Body Diode Characteristics						
Continuous source-drain diode current	I_S	T_C = 25 °C	-	-	59.7	A
Pulse diode forward current (t_p = 100 µs)	I_{SM}		-	-	300	
Body diode voltage	V_{SD}	I_S = 5 A	-	0.72	1.1	V
Body diode reverse recovery time	t_{rr}	I_F = 10 A, di/dt = 100 A/µs, T_J = 25 °C	-	29	58	ns
Body diode reverse recovery charge	Q_{rr}		-	23	46	nC
Reverse recovery fall time	t_a		-	15	-	ns
Reverse recovery rise time	t_b		-	14	-	

Notes

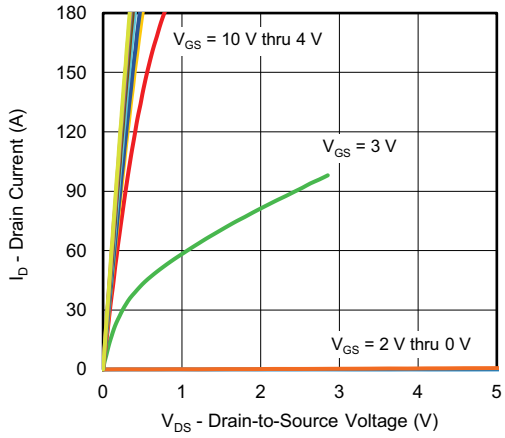
g. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %

h. Guaranteed by design, not subject to production testing

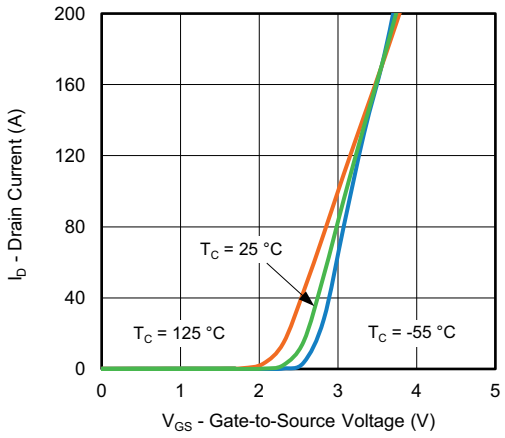
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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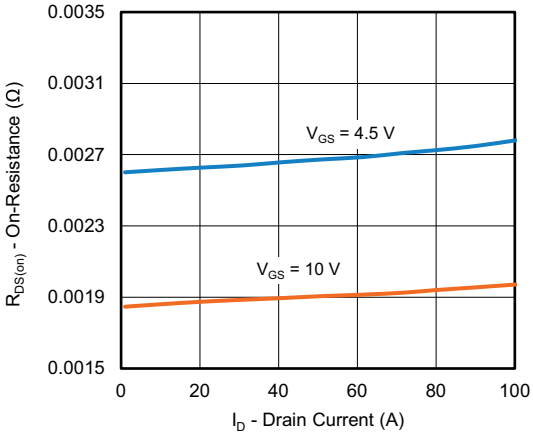
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



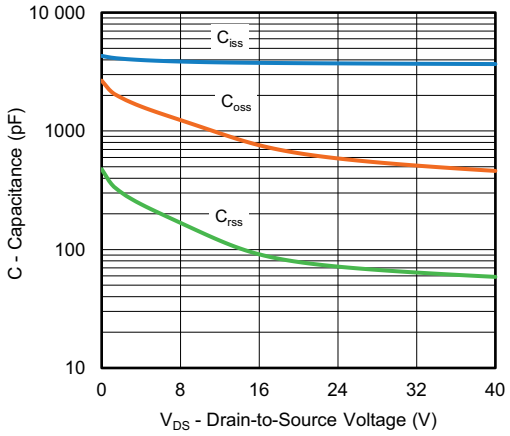
Output Characteristics



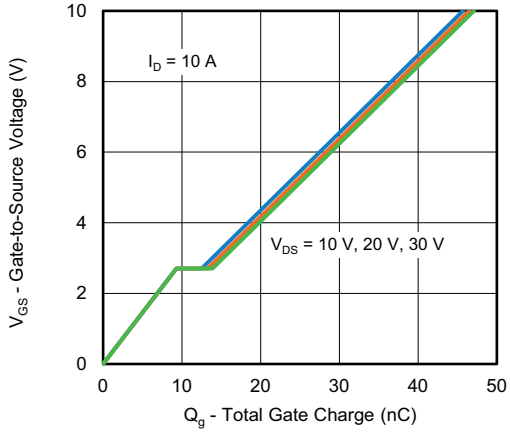
Transfer Characteristics



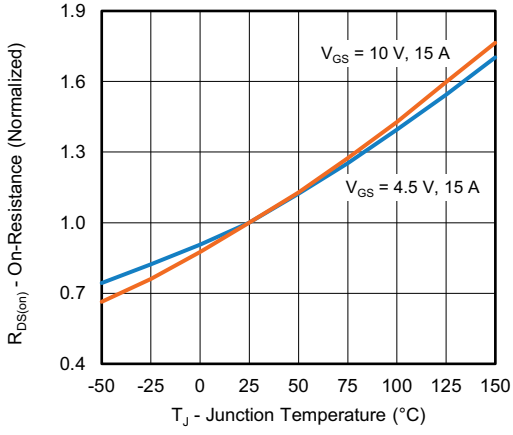
On-Resistance vs. Drain Current



Capacitance



Gate Charge

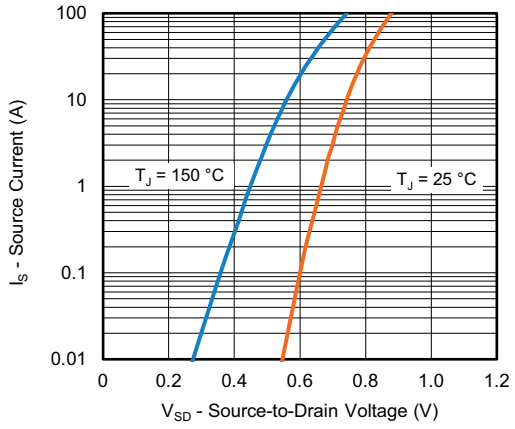


On-Resistance vs. Junction Temperature

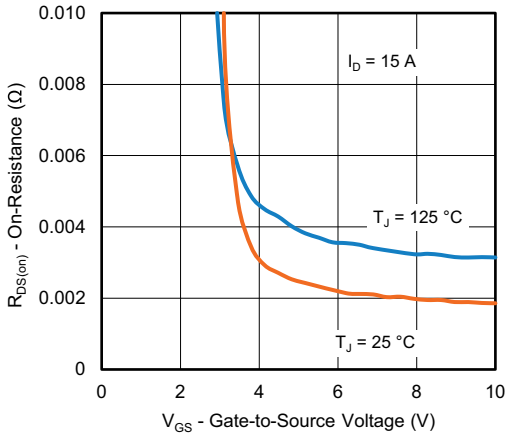
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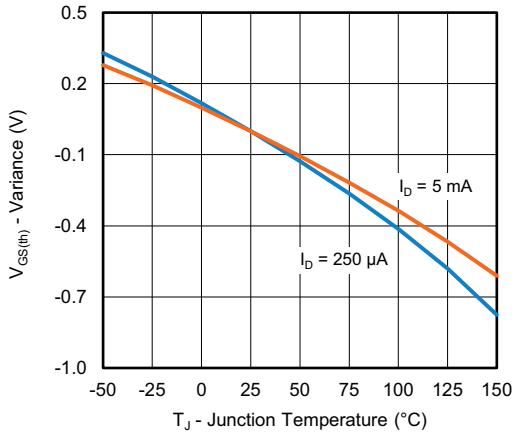
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



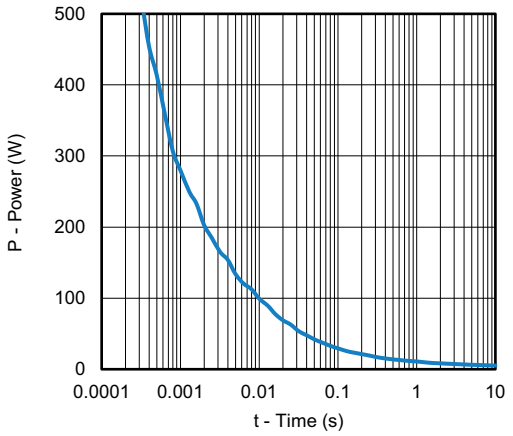
Source-Drain Diode Forward Voltage



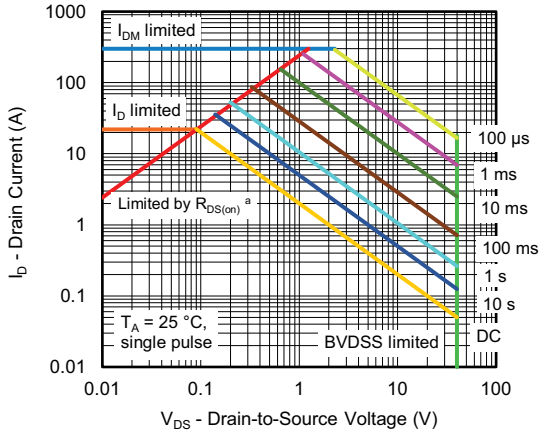
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



Single Pulse Power, Junction-to-Ambient



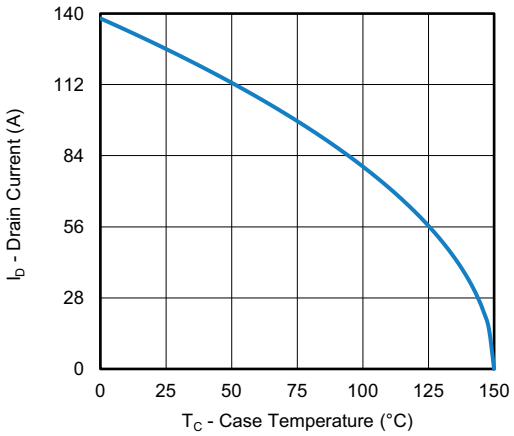
Safe Operating Area

Note

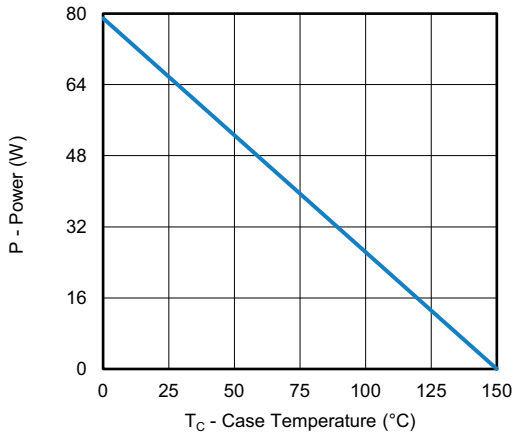
a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

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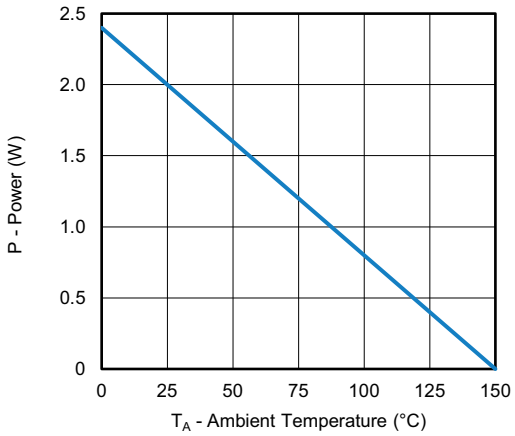
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating [a]



Power, Junction-to-Case



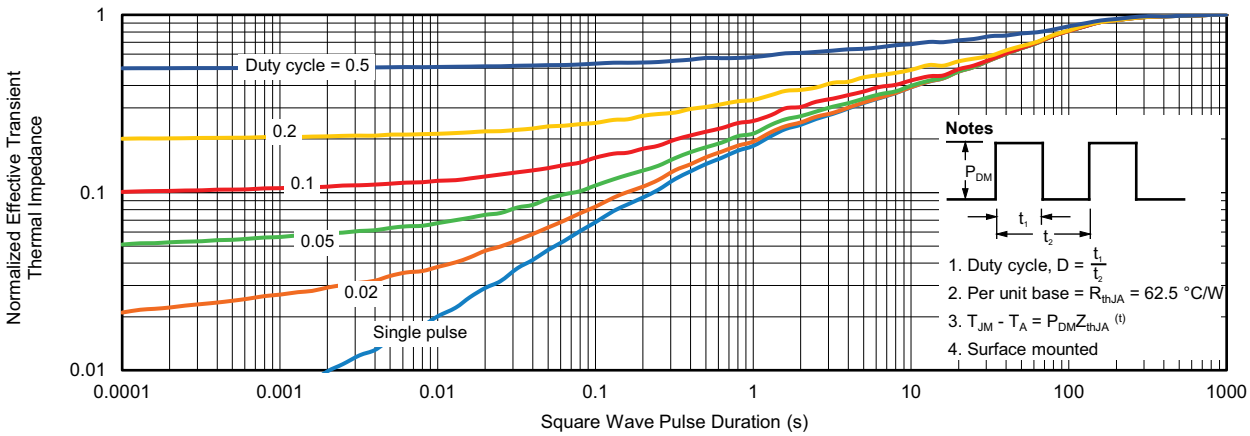
Power, Junction-to-Ambient

Note

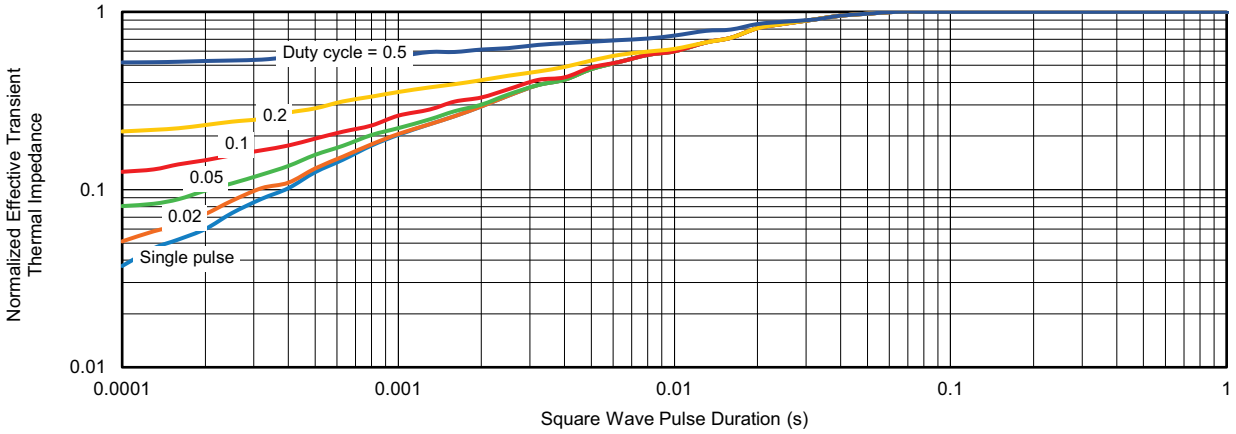
a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



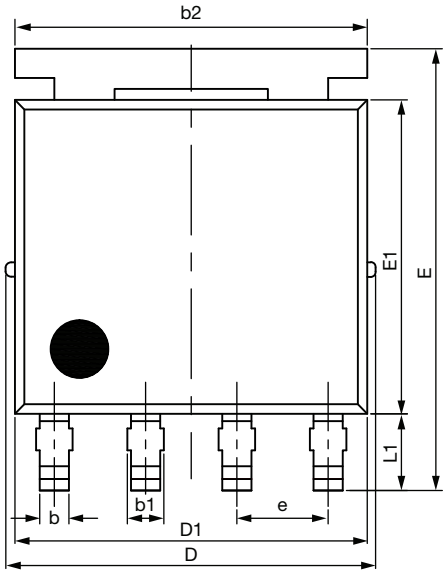
Normalized Thermal Transient Impedance, Junction-to-Case

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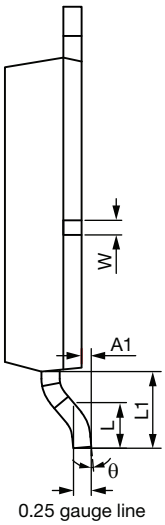
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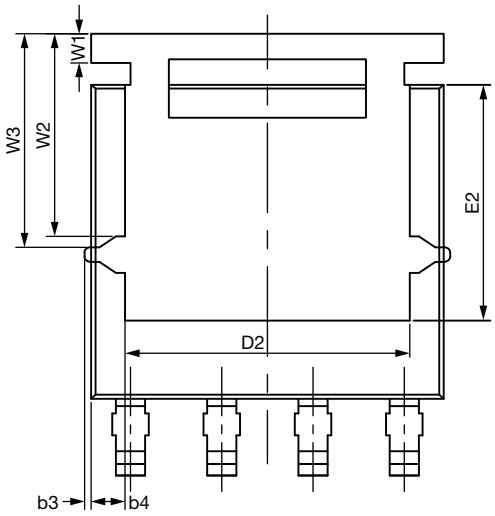
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PowerPAK® SO-8L Case Outline 1

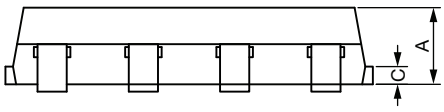


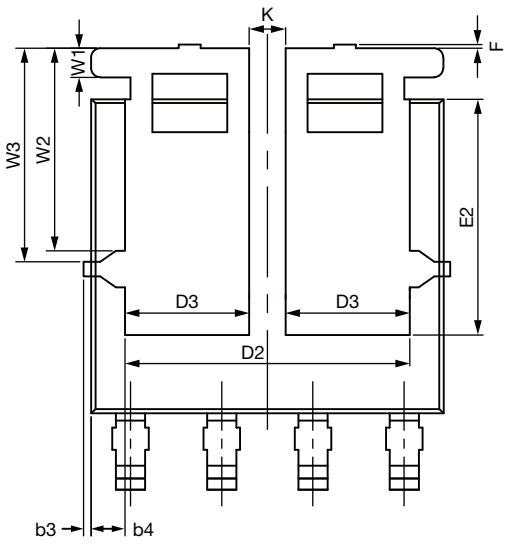
Topside view





Backside view (single)





Backside view (dual)

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DIM.	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	1.00	1.07	1.14	0.039	0.042	0.045
A1	0.00	-	0.127	0.00	-	0.005
b	0.33	0.41	0.48	0.013	0.016	0.019
b1	0.44	0.51	0.58	0.017	0.020	0.023
b2	4.80	4.90	5.00	0.189	0.193	0.197
b3	0.094			0.004		
b4	0.47			0.019		
c	0.20	0.25	0.30	0.008	0.010	0.012
D	5.00	5.13	5.25	0.197	0.202	0.207
D1	4.80	4.90	5.00	0.189	0.193	0.197
D2	3.86	3.96	4.06	0.152	0.156	0.160
D3	1.63	1.73	1.83	0.064	0.068	0.072
e	1.27 BSC			0.050 BSC		
E	6.05	6.15	6.25	0.238	0.242	0.246
E1	4.27	4.37	4.47	0.168	0.172	0.176
E2	3.18	3.28	3.38	0.125	0.129	0.133
F	-	-	0.15	-	-	0.006
L	0.62	0.72	0.82	0.024	0.028	0.032
L1	0.92	1.07	1.22	0.036	0.042	0.048
K	0.51			0.020		
W	0.23			0.009		
W1	0.41			0.016		
W2	2.82			0.111		
W3	2.96			0.117		
θ	0°	-	10°	0°	-	10°
ECN: S19-0643-Rev. E, 05-Aug-2019 DWG: 5976						

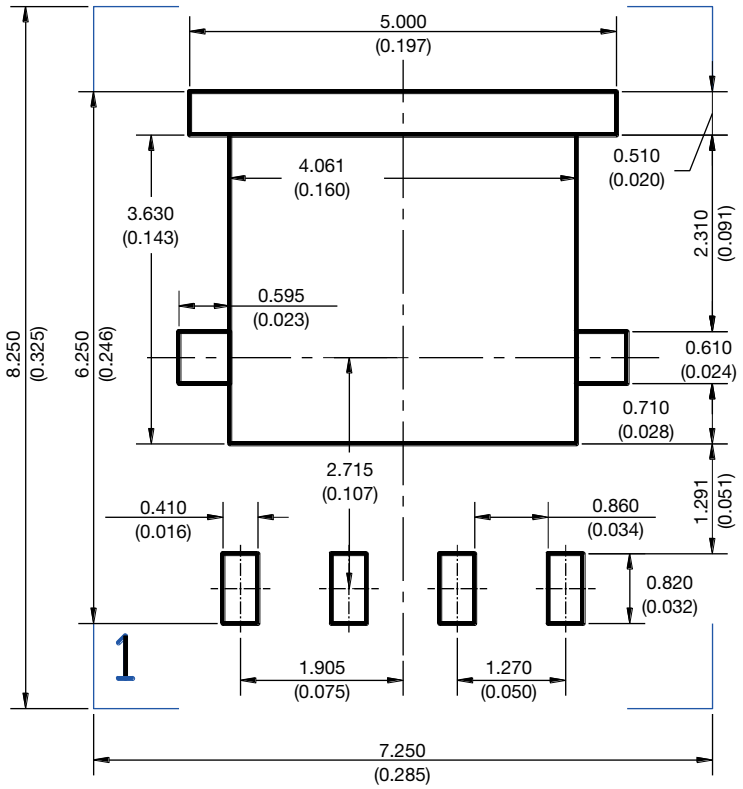
Note

- Millimeters will gover

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RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L SINGLE



Recommended Minimum Pads
Dimensions in mm (inches)

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